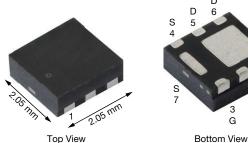
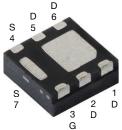
www.vishay.com

Vishay Siliconix

Automotive N-Channel 20 V (D-S) 175 °C MOSFET

PowerPAK® SC-70W-6L Single





Marking Code: QZXXXX

PRODUCT SUMMARY				
V _{DS} (V)	20			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0175			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 2.5 \text{ V}$	0.0240			
I _D (A)	9			
Configuration	Single			

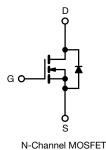
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- Wettable flank terminals
- 100 % R_a and UIS tested
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





HALOGEN FREE



ORDERING INFORMATION	
Package	PowerPAK SC-70W-6L
Lead (Pb)-free and halogen-free	SQA446CEJW (for detailed order number please see www.vishay.com/doc?79776)

ABSOLUTE MAXIMUM RATIN	GS (T _C = 25 °C, unles	s otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	20		
Gate-source voltage		V _{GS}	± 12	V	
Continuous drain current ^a	T _C = 25 °C		9		
	T _C = 125 °C	- I _D	9		
Continuous source current (diode conduction) a		I _S	9	Α	
Pulsed drain current ^a		I _{DM}	36		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	26		
Single pulse avalanche energy	L = 0.1 IIII	E _{AS}	33.8	mJ	
Maximum power dissipation	T _C = 25 °C	р	13.6	W	
	T _C = 125 °C	P_{D}	4.5		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) d, e		-	260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient PC	CB mount c	R_{thJA}	90	°C/W	
Junction-to-case (drain)		R _{thJC}	11]	

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70W-6L is a leadless package and features wettable flank terminals. The end of the lead terminal is plated with tin.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		•			•	I.	L	
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		20	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		0.6	1.0	1.3		
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$		-	-	± 100	nA	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1		
		V _{GS} = 0 V	V _{DS} = 20 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 20 V, T _J = 175 °C	-	-	250		
On-state drain current ^a	I _{D(on)}	$V_{GS} = 4.5 \text{ V}$	$V_{DS} \ge 5 \text{ V}$	9	-	-	Α	
B		$V_{GS} = 4.5 \text{ V}$	I _D = 4.5 A	-	0.0142	0.0175		
	_	V _{GS} = 4.5 V	I _D = 4.5 A, T _J = 125 °C	-	-	0.0250		
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 4.5 V	I _D = 4.5 A, T _J = 175 °C	-	-	0.0289	Ω	
		V _{GS} = 2.5 V	I _D = 3 A	-	0.0194	0.0240		
Forward transconductance b	9fs	V_{DS}	= 10 V, I _D = 4 A	-	28	-	S	
Dynamic ^b								
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 10 V, f = 1 MHz	-	649	910	pF	
Output capacitance	Coss			-	174	245		
Reverse transfer capacitance	C _{rss}]		-	71	100		
Total gate charge ^c	Qg			-	6.5	10	nC	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 4.5 \text{ V}$	$V_{DS} = 10 \text{ V}, I_{D} = 8 \text{ A}$	-	1.6	-		
Gate-drain charge ^c	Q _{gd}			-	1.6	-		
Gate resistance	R _g	f = 1 MHz		0.5	1.0	1.5	Ω	
Turn-on delay time ^c	t _{d(on)}				10	16		
Rise time ^c	t _r	$V_{DD} = 10 \text{ V, } R_L = 4 \Omega$ $I_D \cong 2.5 \text{ A, } V_{GEN} = 4.5 \text{ V, } R_g = 1 \Omega$		-	19	30	- ns	
Turn-off delay time ^c	t _{d(off)}			-	19	30		
Fall time ^c	t _f			-	8	15		
Source-Drain Diode Ratings and Charact	eristics ^b							
Pulsed current ^a	I _{SM}			-	-	36	Α	
Forward voltage	V _{SD}	I _F = 4.5 A, V _{GS} = 0 V		-	0.77	1.2	V	
Body diode reverse recovery time	t _{rr}			-	11	22	ns	
Body diode reverse recovery charge	Q _{rr}	I _F = 2 A, di/dt = 100 A/μs		-	3.7	8	nC	
Reverse recovery fall time	ta			-	6	-		
Reverse recovery rise time	t _b			-	5	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-0.64	-	Α	

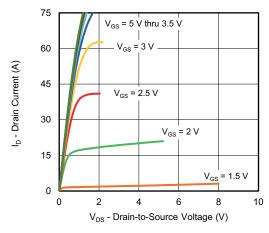
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

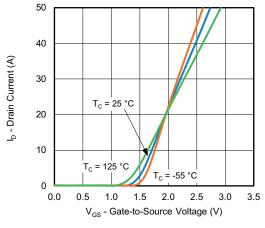
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



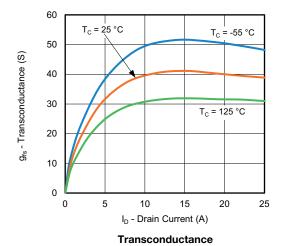
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Output Characteristics



Transfer Characteristics



0.05

(C) 0.04

O 0.03

O 0.02

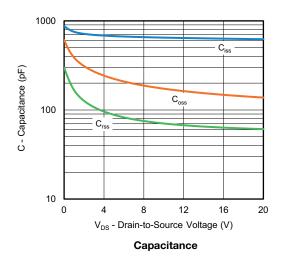
O 0.01

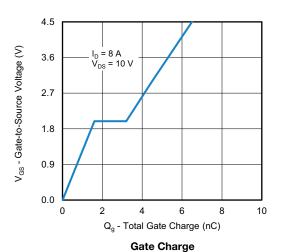
O 0.00

O 0 5 10 15 20 25 30

I_D - Drain Current (A)

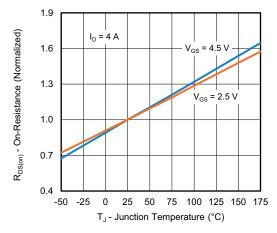
On-Resistance vs. Drain Current



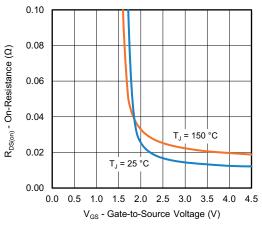




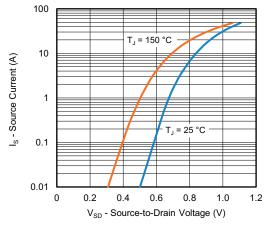
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



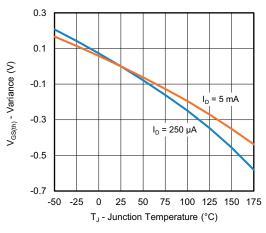
On-Resistance vs. Junction Temperature



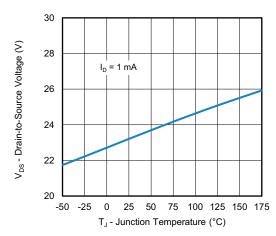
On-Resistance vs. Gate-to-Source Voltage



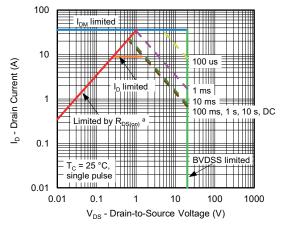
Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



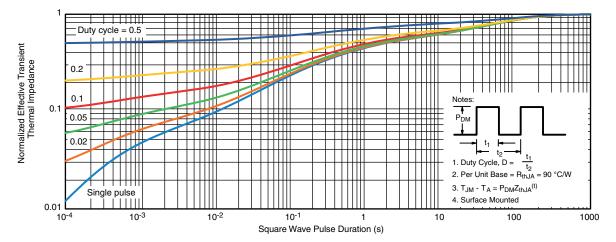
Safe Operating Area

Note

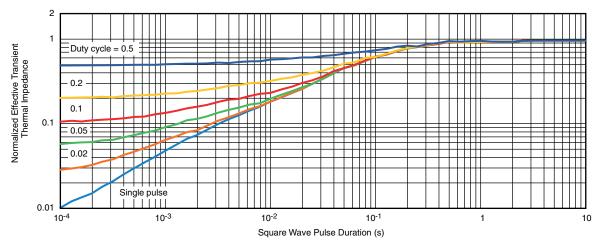
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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